

SANYO Semiconductors DATA SHEET

2SA2186 — PNP Epitaxial Planar Silicon Transistor

High-Current Switching Applications

Applications

· Voltage regulators, relay drivers, lamp drivers, electrical equipment.

Features

- · Adoption of MBIT processes.
- · High current capacity.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-50	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	VEBO		-6	V
Collector Current	IC		-2	Α
Collector Current (Pulse)	ICP		-4	Α
Base Current	IΒ		-400	mA
Collector Dissipation	PC		0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =-40V, I _E =0A			-1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0A			-1	μΑ
DC Current Gain	hFE1	V _{CE} =-2V, I _C =-100mA	200		560	
	hFE2	VCE=-2V, IC=-1.5A	40			
Gain-Bandwidth Product	fΤ	V _{CE} =-10V, I _C =-300mA		420		MHz
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		16		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=-1A, IB=-50mA		-0.22	-0.43	V
Base-to-Emitterr Saturation Voltage	V _{BE} (sat)	I _C =-1A, I _B =-50mA		-0.9	-1.2	V

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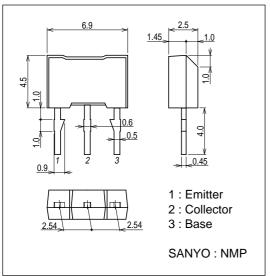
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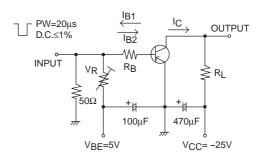
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=-10μA, IE=0A	-50			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=-10μA, IC=0A	-6			V
Turn-On Time	ton	See specified Test Circuit.		35		ns
Storage Time	t _{stg}	See specified Test Circuit.		200		ns
Fall Time	tf	See specified Test Circuit.		24		ns

Package Dimensions

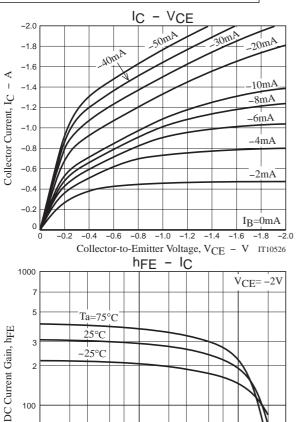
unit: mm 7519-003



Switching Time Test Circuit



 $I_{C}=10I_{B1}=-10I_{B2}=-0.7A$



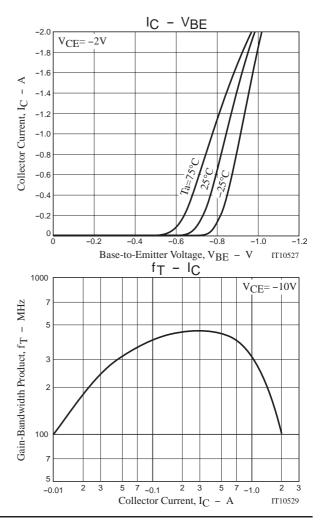
5 7 -0.1 2 3 5 Collector Current, I_C - A

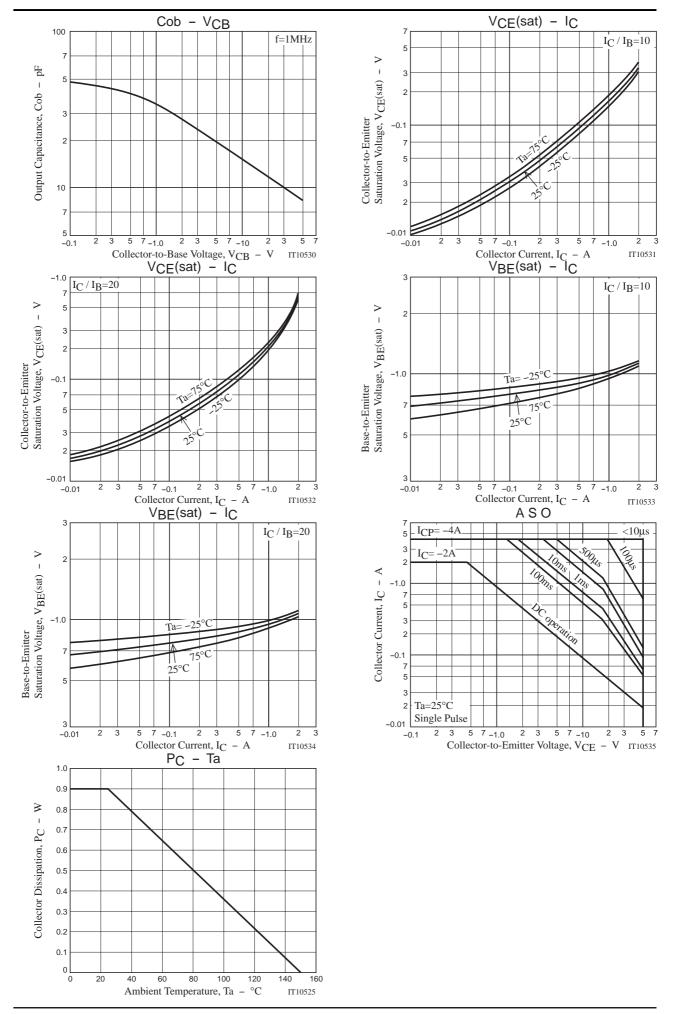
5 7 -1.0

IT10528

−25°C

100





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